

Cite this: *Mater. Horiz.*, 2024, 11, 726Received 13th June 2023,  
Accepted 15th November 2023

DOI: 10.1039/d3mh00907f

rsc.li/materials-horizons

# Constructing asymmetric gradient structures to enhance the energy storage performance of PEI-based composite dielectrics†

Dong Yue,<sup>ab</sup> Wenchao Zhang,<sup>\*ab</sup> Puzhen Wang,<sup>ab</sup> Yong Zhang,<sup>ab</sup> Yu Teng,<sup>ab</sup>  
Jinghua Yin<sup>ab</sup> and Yu Feng<sup>ab</sup>

Enhancing the high electric field resistance and energy storage capacity of polymer dielectrics has been a long-standing challenge for the iterations of power equipment. Synergistic inhibition of carrier injection and transport is vital to energy storage performance improvement. Herein, promising polymer polyetherimide (PEI) was employed as a matrix and wider bandgap boron nitride nanosheets (BNNSs) were used as a reinforcing filler. Utilizing high-throughput stochastic breakdown simulations with the distribution characteristics of BNNSs as parameters, a series of topological gradient structures with the potential to enhance performance were obtained, thereby shortening the experimental cycle. Changing the BNNS distribution of symmetric/asymmetric and positive/inverse gradients, as well as the total and gradient contents of BNNSs, means that the position and condition of the surface barrier layer and central hinder layer change, which influences the energy storage performance of the polymer at room temperature and high temperature. Remarkably, the asymmetric gradient structure composite dielectrics exhibited excellent performances. Among them, the PEI-based composite dielectric with 2 vol% BNNS asymmetric inverse gradient distribution (gradient content of 1 vol%) achieved energy densities of 8.26 and 4.78 J cm<sup>-3</sup> at room temperature and 150 °C, respectively. The asymmetric gradient structure design strategy holds great promise for optimizing the energy storage capacity of polymer dielectric capacitors.

## 1. Introduction

Breakthrough and proliferation of energy storage technology will enable energy distribution and adaptation across time and space, which is revolutionary for the generation and

### New concepts

This work demonstrates a novel design approach for polymer dielectrics with asymmetric gradient structures. By adjusting the distribution characteristics of inorganic fillers, while considering the carrier injection and transport mechanisms, the surface barrier layer and internal hinder layer in different positions and states can be constructed. The combination of simulation and experiment intelligently and effectively selects the optimal range of parameters and results in a asymmetric gradient composite dielectric with significantly improved energy storage performance. This route holds potential for application in more polymer systems and provides a new composite structure preparation strategy for electrical equipment operating in different environments.

consumption of energy.<sup>1-3</sup> Dielectric capacitors possess a high power density and rapid charge/discharge ability within a short time, making them extensively applicable in domains such as high-power electronic devices, new energy vehicles, and grid storage systems.<sup>4-6</sup> Compared to inorganic dielectric capacitors, polymer dielectric capacitors exhibit characteristics such as high breakdown strength ( $E_b$ ), low dielectric loss ( $\tan \delta$ ), and excellent processability, providing a broader scope for the structural design of dielectric film capacitors.<sup>7-9</sup> However, polymer dielectric capacitors suffer from relatively low energy storage density ( $U_e$ ), which limits their practical applications. The most typical representative of commercial dielectric capacitors, biaxially oriented polypropylene (BOPP), exhibits an  $U_e$  of only 2–3 J cm<sup>-3</sup>, impeding the development of dielectric film capacitors towards miniaturization and integration. In practical applications, linear dielectrics are desirable since the stored energy in them can be discharged to the utmost extent. The  $U_e$  of a dielectric capacitor in the linear approximation is given by  $U_e = 1/2 \epsilon_0 \epsilon_r E_b^2$  with  $\epsilon_0$  as the vacuum dielectric constant ( $8.85 \times 10^{-12}$  F m<sup>-1</sup>) and  $\epsilon_r$  as the

<sup>a</sup> Key Laboratory of Engineering Dielectrics and Its Application, Ministry of Education, Harbin University of Science and Technology, Harbin, 150080, P.R. China.  
E-mail: zhangwenchao@hrbust.edu.cn, fengyu@hrbust.edu.cn

<sup>b</sup> School of Electrical and Electronic Engineering, Harbin University of Science and Technology, Harbin, 150080, P.R. China

† Electronic supplementary information (ESI) available. See DOI: <https://doi.org/10.1039/d3mh00907f>

relative dielectric constant. It can be seen that the  $U_e$  of the dielectric depends on both  $\epsilon_r$  and  $E_b$ . In addition, in linear dielectrics, the  $U_e$  is positively correlated with the square of the  $E_b$ , which indicates that the  $E_b$  has a greater driving effect on the  $U_e$  than the  $\epsilon_r$ .

Adding inorganic materials with different physical and chemical properties into the polymer matrix serves as a common strategy for reinforcement.<sup>10</sup> Non-0D filler orientation in the matrix can further optimize the performance by mitigating electric field distortion and increasing breakdown path tortuosity.<sup>11</sup> Notably, 2D nanosheet inorganic fillers such as boron nitride (BN) and molybdenum sulfide (MoS<sub>2</sub>) exhibit a remarkable ability to block the breakdown path in a wider region.<sup>12,13</sup> Nevertheless, it is difficult to inhibit both carrier injection and transport in this approach, resulting in limited performance improvements. Despite efforts to modify the surface of inorganic fillers to further improve  $U_e$  by strengthening the organic–inorganic interface, these often come at the cost of cumbersome processes. The multi-layer structure design strategy provides more imagination for performance improvement.<sup>14–18</sup> The layer structure design can give different functional properties to each layer, and the mesoscopic interface formed between the adjacent layers can also block the breakdown path, twisting the breakdown path between layers. Bai *et al.*<sup>19</sup> proposed a sandwich-structured polymer composite dielectric composed of a polarization layer and an insulating layer, with the multi-layer structure and filler synergy achieving the  $U_e$  enhancement. Jiang *et al.*<sup>20</sup> introduced a structured design of multilayered polymer composite dielectrics capable of integrating the inhibited effects of dielectric/electrode and dielectric/dielectric interfaces on charge injection and migration, remarkably enhancing the  $E_b$  and  $U_e$ . However, another challenge was exposed, as the dielectric performance varies when adjacent layers have different functionalities, resulting in a dielectric mismatch between layers. This leads to local electric field distortion and severe carrier transport. The multi-layer gradient structure refines the spatial distribution and breaks this barrier.<sup>21–23</sup> Jiang *et al.*<sup>24</sup> designed the gradient distribution strategy of BaTiO<sub>3</sub> in the P(VDF–HFP) matrix by

using the improved electrospinning process. The gradient structure effectively delayed the breakdown path development. Our previous work has also demonstrated that the gradient structure greatly improved the energy storage performance of the polymer.<sup>25,26</sup>

Hence, in this paper, a performance enhancement strategy by adjusting the BNNS distribution characteristics in the PEI matrix is proposed. It is proven that the function of the surface barrier layer and central hinder layer at both carrier injection and transport is to reduce the distance between the functional layers, which can lower the carrier acceleration distance and energy after acceleration. Importantly, the composite dielectrics with an asymmetric inverse structure exhibit higher withstand breakdown and energy storage capacity, and present outstanding performance even at high temperature. This work pointed out the importance of a topological gradient structure and different functional layer positions. It does not involve more complicated processes of inorganic filler modification or lengthy technical challenges in new monomer development, and provides a new design route for the development and mass production of high-energy storage polymer dielectrics.

## 2. Experimental section

### 2.1 Materials

Polyetherimide (PEI) was provided by PolyK Technologies. Boron nitride nanosheets (BNNSs) were provided by Nanjing Suzhan Intelligent Technology Co., Ltd. 1-Methyl-2-pyrrolidinone (NMP) was provided by Tianjin Bailunsi Biotechnology Co., Ltd.

### 2.2 Preparation of the polymer dielectrics

As shown in Fig. S1 (in the ESI<sup>†</sup>), a certain amount of BNNSs was taken and dispersed in the NMP solution by sonication. Then, the PEI particles were added to the above dispersion in proportion, heated and stirred until completely dissolved. The obtained mixed solution was placed in a vacuum oven to discharge the bubbles. The mixed solutions with different BNNS contents were transferred to syringes, and the mixed solutions underwent high-speed directional electrospinning in the designed gradient order layer by layer at an electric field of 0.2 kV mm<sup>-1</sup> and the directional rotary receiver speed of 2000 rpm. The as-spun fiber mats were dried to remove the organic solvents. They were hot-pressed at 220 °C for 5 min under a pressure of 15 MPa and then quenched in ice water to finally obtain dense gradient composite dielectrics.

### 2.3 Microstructure characterization and performance measurement

The morphology and elemental mapping of nanosheets were measured by transmission electron microscopy (TEM, FEI Tecnai G2 F20). The cross-sectional morphology and elemental mapping of the polymer composite dielectrics were characterized by scanning electron microscopy (SEM, Hitachi SU8020). The phase structure of the nanosheets and polymer composite



Yu Feng

*Grateful to Materials Horizons for a decade of reporting on the newest advancements and cutting-edge research in materials science. It was a great honor to have been selected as one of the Materials Horizons Emerging Investigator in 2022, and this recognition is a significant highlight of my research journey. Looking forward to continued collaboration, and sharing more advancements in polymer composites with excellent insulation and energy storage*

*performance. Congratulations on the 10th anniversary and best wishes to Materials Horizons.*

dielectrics was measured by X-ray diffraction (XRD, PANalytical Empyrean). The chemical construction of the polymer composite dielectrics was characterized by Fourier transform infrared spectroscopy (FT-IR, Bruker Vector-22). The luminescence intensity of the polymer composite dielectrics was measured with a photoluminescence test system (PL, FLS1000). The Al electrodes (9 mm and 3 mm in diameter) were evaporated on two sides of the polymer composite dielectrics for the following electric measurements. The dielectric constant, dielectric loss, and AC conductivity measurements of the polymer composite dielectrics were performed using a Concept 40 broadband dielectric spectrometer at room temperature and high temperature from 1 Hz to  $10^6$  Hz. The breakdown and energy storage performances of the polymer composite dielectrics at room temperature and high temperature were investigated using a DC breakdown test system (a voltage ramp of  $500 \text{ V s}^{-1}$ ) and a ferroelectric polarized loop test system (at  $10^2$  Hz) from PolyK Technologies, respectively.

#### 2.4 Stochastic breakdown model

A modified stochastic model<sup>27</sup> was employed based on the one proposed by Niemeyer *et al.*<sup>28</sup> to study the internal electric field distribution and breakdown path development of the polymer dielectrics under the applied electric field. In the stochastic breakdown model, the breakdown probability  $P(r)$  is written as:

$$P(r) = \frac{E(r)^2}{E_b(r)^2} / \sum \frac{E(r)^2}{E_b(r)^2} \quad (1)$$

where  $E(r)$  is the electric field of a local point determined by the externally applied voltage and the microstructure,  $E_b(r)$  is the corresponding intrinsic breakdown strength determined by the polymer dielectrics, and the summation in the denominator is the sum over all points that the local electric field exceeds the breakdown strength. The internal electric field distribution is obtained by solving the electric equilibrium equation using the spectral iterative perturbation method.<sup>29</sup> More details of the stochastic breakdown model can be found in the ESI.†

### 3. Results and discussion

Fig. 1a depicts the schematics of the different topological gradient structures. Through adjustment of the BNNS distribution within the matrix, a symmetric positive or inverse gradient structure is formed, with the content changing from both sides towards the center gradient. Additionally, an asymmetric positive or inverse gradient structure is created, with the content increasing or decreasing from the top towards the center gradient, and continuing to increase or decrease from the center towards the bottom content. Before the experiment began, high-throughput stochastic breakdown simulation was used to verify the feasibility of the experiment design and find the optimal parameter range to shorten the experiment cycle. The total content and gradient content of BNNSs are set at 0.5, 1, 1.5, 2, 2.5, 3, 3.5, and 4 vol%, respectively, to achieve 144 various topological gradient structures. Subsequently, it is named by combining the symmetric/asymmetric (S/A), positive/inverse (P/I), gradient (G), and total content and gradient content of BNNSs. For example, the AIG (2/1) composite dielectric refers to an asymmetric inverse gradient composite dielectric with a BNNSs total content of 2 vol% and a BNNSs gradient content of 1 vol%. Fig. S2–S5 (in the ESI†) show the simulated temporal development of the breakdown fraction of different PEI-based composite dielectrics, while Fig. 1b shows the improvement or decline degree of all composite structures compared with the PEI matrix. The breakdown path development is obviously restricted *via* constructing a 3D topological structure, resulting in varying degrees of improvement of breakdown performance. Meanwhile, the improvement in the breakdown performance is weak at small or large total content of BNNSs, and the difference in improvement between adjacent gradient contents of BNNSs is indistinguishable. Hence, the total content and gradient content of BNNSs were considered 1, 2, and 3 vol% in the subsequent experiments, respectively. The improvement mechanism of the topological gradient structure with respect to the energy storage performance was investigated across four dimensions: total content and gradient content of

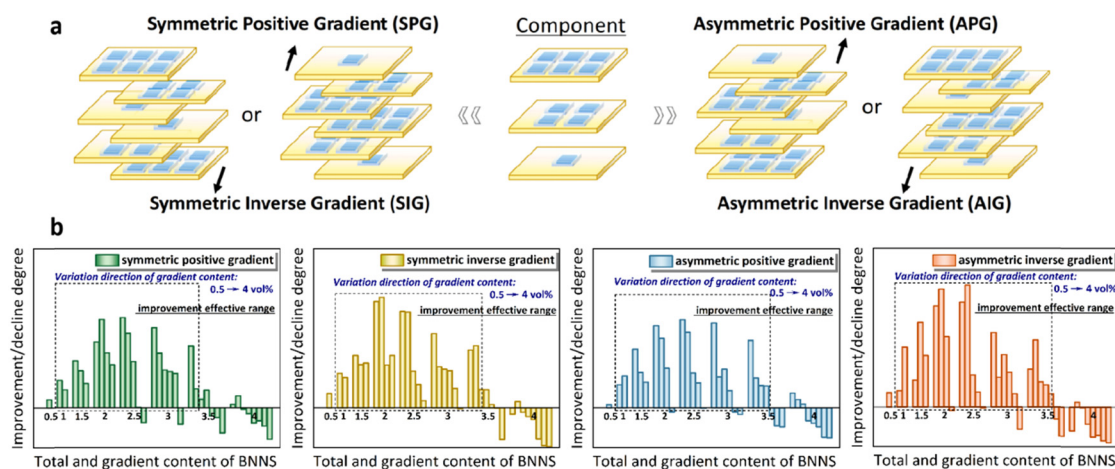


Fig. 1 (a) Design concept of PEI-based composite dielectrics with different topological gradient structures. (b) Improvement or decline degree of all composite structures compared with the matrix.

BNNs, symmetric gradient and asymmetric gradient, positive gradient and inverse gradient.

Fig. 2a shows the TEM image of BNNs, which can be seen to exhibit a distinct 2D sheet structure with a size of about 100 nm. Elemental mappings show the distribution of B and N elements, which is in perfect agreement with that in the selected scan area, as shown in Fig. 2b–d. The AFM image shows that the thickness of BNNs is  $\sim 10$  nm (Fig. S6 in the ESI†). It can be observed from the XRD pattern that the diffraction peaks corresponding to BNNs at  $26.5^\circ$ ,  $41.6^\circ$ , and  $55^\circ$  correspond to (002), (100), and (004) crystal planes, respectively (Fig. S7 in the ESI†). The SEM images of PEI-based composite dielectrics with different topological gradient structures are shown in Fig. 2e. The alternating high-speed directional electrospinning process enables precise control over the components of the topological gradient structure owing to manipulating the spinning time of each layer, while ensuring consistent hot-pressing conditions. All PEI-based composite dielectrics have a thickness of  $\sim 12$   $\mu\text{m}$ , exhibit a high-density structure and lack evident defects such as stratification or holes. Elemental mappings were performed to visually observe the distribution characteristics of BNNs in different gradient structures, as shown in Fig. 2e. BNNs doping content in the symmetric positive gradient structure increases from both sides to the center, forming a “ $\Lambda$ ” shape; BNNs doping content in the symmetric inverse gradient structure decreases from both sides to the center, forming a “V” shape; BNNs doping content in the asymmetric positive gradient structure first increases

from the top to the center, then rapidly decreases, and increases again from the center to the bottom; BNNs doping content in the asymmetric inverse structure demonstrates an inverse pattern, and BNNs doping content decreases from the top to the center, followed by a rapid increase, and then another decrease from the center to the bottom. The elemental mapping results confirm that the prepared PEI-based composite dielectrics with different gradient structures conform to the expected design and distribution characteristics.

The XRD patterns of all PEI-based composite dielectrics show comparable structural characteristics (Fig. S8 in the ESI†). The broad scattering peak observed around  $2\theta = 23^\circ$  corresponds to the characteristic diffraction peak of the PEI matrix. With an increase in the BNNs total content, the peak position of PEI-based composite dielectrics gradually shifts to the left. According to Bragg's law:

$$n\lambda = 2d \sin \theta \quad (2)$$

where  $n$  is the integer order of diffraction for the crystal,  $\lambda$  is the wavelength of the X-ray,  $d$  is the interplanar spacing, and  $\theta$  is the diffraction angle. The  $\theta$  decrease indicates the  $d$  increase when  $\lambda$  is fixed, providing more space for charge accumulation, thereby affecting the dielectric and breakdown performances of the PEI-based composite dielectrics. Additionally, the peak at  $2\theta = 26.5^\circ$  corresponds to the (002) crystal plane of BNNs, but at a lower BNNs content, its intensity is masked by the high scattering intensity of the PEI matrix, resulting in a less

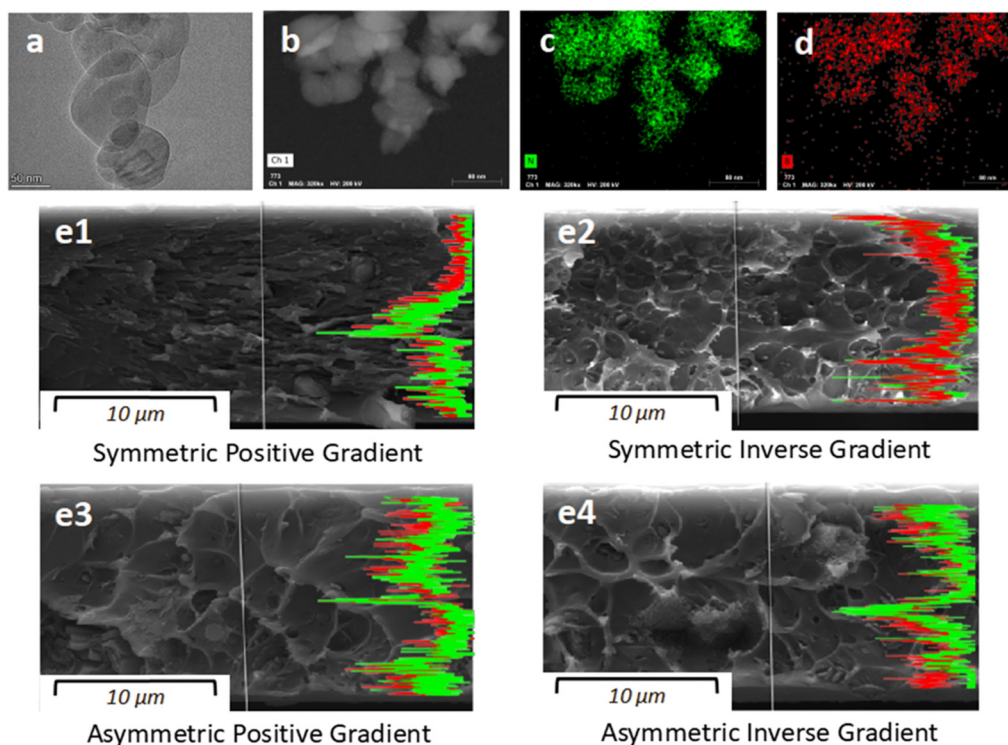


Fig. 2 The TEM image (a) and elemental mappings (b)–(d) of the BNNs. (e) The cross-sectional SEM images and elemental mappings of the gradient composite dielectrics.

observable characteristic diffraction peak. The FTIR spectra of pure PEI and PEI-based composite dielectrics with different gradient structures are shown in Fig. S9 (in the ESI†). The absorption peaks at 750 and 1380  $\text{cm}^{-1}$  correspond to the C–N bending and C–N stretching, respectively. The absorption peaks at 1720 and 1780  $\text{cm}^{-1}$  belong to the asymmetric and symmetric stretching of the imide carbonyl group in the PEI matrix, respectively. The absorption peak at 1100  $\text{cm}^{-1}$  belongs to the B–N stretching of BNNs.

Fig. S10 (in the ESI†) shows the  $\epsilon_r$  and  $\tan \delta$  curves with respect to frequency for pure PEI and PEI-based composite dielectrics. The  $\epsilon_r$  of all dielectrics continuously decreases with increasing frequency, which is attributed to the dipole orientation polarization having difficulty keeping up with the external electric field at high frequency, resulting in an inability to establish polarization in time. The  $\tan \delta$  tends to first decrease and then increase with increasing frequency as the change time of the electric field becomes shorter as the frequency increases, making it difficult for the electrons in the dielectric to move with it. However, the inherent loss increases as the frequency continues to increase, leading to a gradual rise in  $\tan \delta$ .<sup>30</sup> The  $\epsilon_r$  and  $\tan \delta$  at  $10^2$  Hz of all dielectrics were extracted, and a histogram was plotted, as shown in Fig. 3. Compared with pure PEI, PEI-based composite dielectrics with gradient structures exhibit varying degrees of enhancement in  $\epsilon_r$ , which is attributed to the enhanced interface polarization provided by the micro-interface between the filler and matrix and the mesoscopic interface of the layer structure. The  $\epsilon_r$  of the gradient composite dielectrics increases constantly with the increase in the total content of BNNs. The total content plays a decisive role in increasing the  $\epsilon_r$  with the same filler and layer numbers.

Furthermore, increasing the total content means a higher number of BNNs in the gradient composite dielectric and an increase in the interface numbers between the organic and inorganic phases, which improves the interfacial polarization. With the gradient content of BNNs increasing, the  $\epsilon_r$  of the gradient composite dielectric initially increases and then decreases because the component units with a higher gradient content often contain single-layer PEI-based composite dielectrics with a higher BNNs content, which can contribute to higher polarization (Fig. S11 in the ESI†). However, the excessively high gradient content compelled a dense distribution of BNNs, leading to larger interfacial charge accumulation and charge obstruction within the dielectric, which decreases the  $\epsilon_r$ .

It is noted that the SIG (3/3) composite dielectric with symmetric inverse gradient obtains the highest  $\epsilon_r$  of 4.30 at  $10^2$  Hz, which is 1.2 times that of pure PEI. The distinction from the above conclusion is that the symmetric inverse gradient structure leads to the dispersion of BNNs on both sides of the gradient composite dielectric. This distribution lowers the probability of agglomeration and charge accumulation, resulting in a more homogeneous electric field within the composite dielectric. Furthermore, the inverse gradient makes the outermost region near the upper electrode have a higher BNNs content, which makes the surface of the gradient composite dielectric have a higher responsiveness to the electric field. This has also been demonstrated in asymmetric gradient composite dielectrics, *i.e.*, the  $\epsilon_r$  of AIG composite dielectrics is higher than that of APG composite dielectrics. The  $\tan \delta$  and AC conductivity ( $\sigma$ ) of all gradient composite dielectrics are maintained at a lower level owing to the wider band gap, lower  $\tan \delta$ , polar B–N chemical bond, and nanosheet structure (Fig. S10 and S12 in the ESI†).

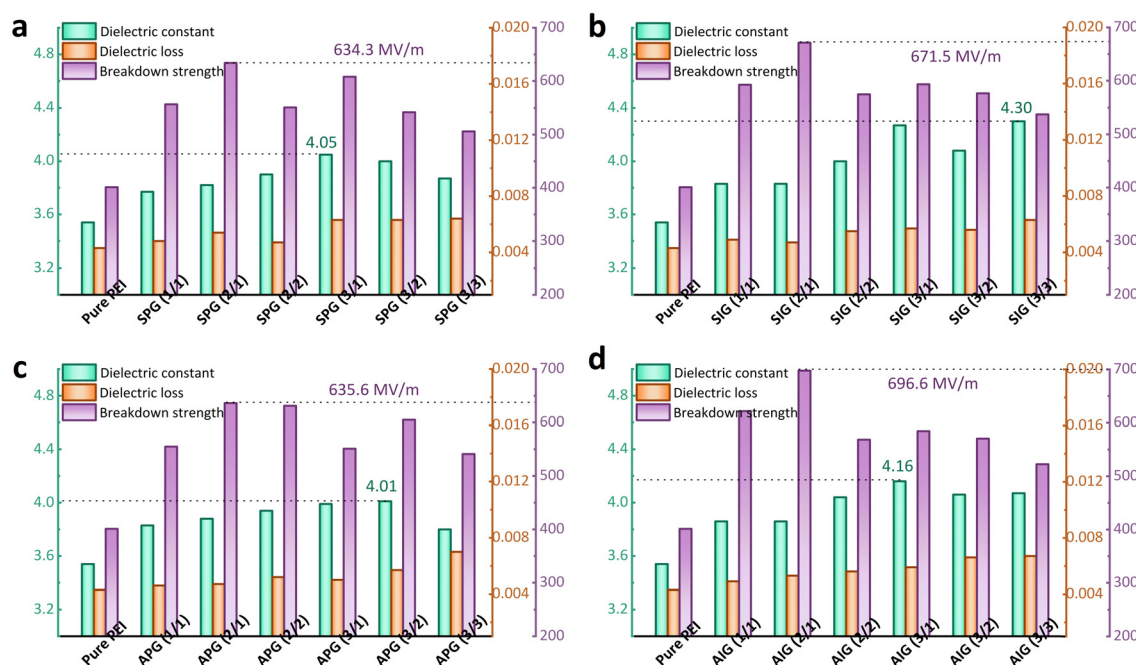


Fig. 3 The dielectric constant and dielectric loss at  $10^2$  Hz, as well as the breakdown strength of (a) SPG, (b) SIG, (c) APG, and (d) AIG composite dielectrics.

The two-parameter Weibull statistical distribution function was used to calculate the characteristic breakdown strength based on the cumulative breakdown probability, and the equation can be described as follows:

$$\ln(-\ln(1 - P(E))) = \beta \ln(E) - \beta \ln(E_b) \quad (3)$$

where  $P(E)$  is the cumulative breakdown probability,  $E$  is the experimentally measured breakdown strength of the polymer dielectrics,  $E_b$  is the breakdown strength at  $P = 63.2\%$ , and the shape parameter  $\beta$  evaluates the scattering of the breakdown data collected in the experiment. The final  $E_b$  of pure PEI and gradient composite dielectrics is shown in Fig. 3 and Fig. S13 (in the ESI†), with  $E_b$  of 400.5, 634.3, 671.5, 635.6, and 696.6 MV m<sup>-1</sup> for pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics, respectively. The higher insulation characteristic of BNNSs increases the sinuosity of the breakdown path,<sup>31,32</sup> the parallel orientation of BNNSs along the dielectric surface and the mesoscopic interface of the multi-layer structure further enhance this effect. In addition, the approximate dielectric constants of PEI (~3.5) and BNNSs (~3.0) achieve dielectric matching between the matrix and the inorganic filler.<sup>33–35</sup> The BNNSs with gradient distribution further reduce the concentration of local electric field, resulting in a lower dielectric mismatch probability between layers, as shown in Fig. S14 (ESI†). The response characteristics of BNNSs to the electric field are obtained by comparing electric field distributions in different microstructures. Two kinds of microstructures are considered, the sandwich structure (BNNSs on both sides) and the gradient structure (take the SIG (2/1) composite dielectric as an example). For the same BNNSs content, variations in dielectric properties between layers generate an electric field gradient at the interface. The BNNSs content on the surface of the sandwich composite dielectric differs significantly from that in the center, creating a noticeable electric field gradient and resulting in non-uniform electric field strength. BNNSs near the center exhibit a pronounced response to the applied electric field. Conversely, the gradient structure realizes the transition of dielectric properties between layers and efficiently slows down the electric field gradient at the interface. Fig. S14d (ESI†) shows that the gradient composite dielectric exhibits no significant electric field distortion and decreases the response of BNNSs to the electric field. With the combination of these advantages, the  $E_b$  of gradient composite dielectrics increased significantly compared with that of pure PEI. As expected, the  $E_b$  of gradient composite dielectrics appears to reach an inflection point when doping with a higher total content of BNNSs. For example, different decrease degrees appear in gradient composite dielectrics with a total content of 3 vol%, which is attributed to the local electric field distortion by BNNSs agglomeration. Moreover, the  $E_b$  of the gradient composite dielectrics also decreases continuously as the gradient content of BNNSs increases. On the one hand, the dielectric matching becomes worse as the gradient content increases, leading to an inability to effectively attenuate the electric field focus. On the other hand, the gradient content increases necessitate the component unit of the gradient composite

dielectric to contain a high content single-layer composite dielectric, which exhibits poor breakdown performance (Fig. S15 in the ESI†).

At the same total content and gradient content of BNNSs, the  $E_b$  of PEI-based composite dielectrics with the inverse gradient is higher than that with the positive gradient. The inverse gradient structure makes the BNNSs content decrease gradually from the upper surface to the center. As a result, large quantities of BNNSs are distributed near the surface contacting the electrode, which effectively raises the injection barrier height. The  $E_b$  of a reasonable asymmetric gradient structure will also be higher than that of a symmetric gradient structure under the same conditions. After the carrier crosses the barrier and is injected into the interior, the voltage sustained inside gradually increases as the acting time of the applied electric field increases, which causes an increase in the carrier migration rate. The breakdown path develops to the region near the bottom electrode inevitably weakening the contribution of the inorganic hinder layer. Hence, it can achieve better breakdown performance by effectively blocking carrier transport in the early and middle stages. Correspondingly, the asymmetric inverse gradient structure adjusts the BNNSs content distribution to inhibit the breakdown path development on the upper surface and in the center during the carrier's early and middle transport processes, and maximally inhibits the carrier migration rate. Among all the topological gradient dielectrics, the AIG (2/1) composite dielectric obtains the highest  $E_b$  of 696 MV m<sup>-1</sup>, which surpasses the  $E_b$  of SIG (2/1) and APG (2/1) composite dielectric, significantly enhancing the withstanding high electric field capability of polymer dielectric. At the same time, Fig. S13 (in the ESI†) also shows that all PEI-based composite dielectrics with a gradient structure exhibit high  $\beta$  values (>10), indicating higher performance reliability, which reflects the excellent compactness achieved by the alternate high-speed electrospinning process combined with the hot-pressing process.

The typical electric displacement dependence of applied electric field ( $D$ - $E$ ) loops of pure PEI and gradient composite dielectrics with elevated electric fields is shown in Fig. S16–S19 (in the ESI†). The relationship between the polarization strength and electric field is approximately linear, and the topological gradient structure significantly optimizes the polarization and withstanding electric field capabilities of the PEI matrix. The  $U_e$  and the corresponding energy storage efficiency ( $\eta$ ) of the polymer dielectrics were calculated through the  $D$ - $E$  loops and are shown in Fig. 4. Based on the synergistic enhancement of  $\epsilon_r$  and  $E_b$ , PEI-based composite dielectrics with a gradient structure achieve higher  $U_e$ . Furthermore, the improvement in  $U_e$  of gradient composite dielectrics is closely related to the enhancement of  $E_b$  since the square of the  $E_b$  has a positive correlation with the  $U_e$ , and the nanosheets limit the enhancement of polarization by restricting the end group steering of the PEI matrix. The AIG (2/1) composite dielectric achieved the highest  $U_e$  of 8.26 J cm<sup>-3</sup>, which is 2.98 times that of pure PEI (2.77 J cm<sup>-3</sup>). More precisely, the excellent ability to inhibit carrier injection and transport simultaneously, as well as the response ability of a higher BNNSs content near the

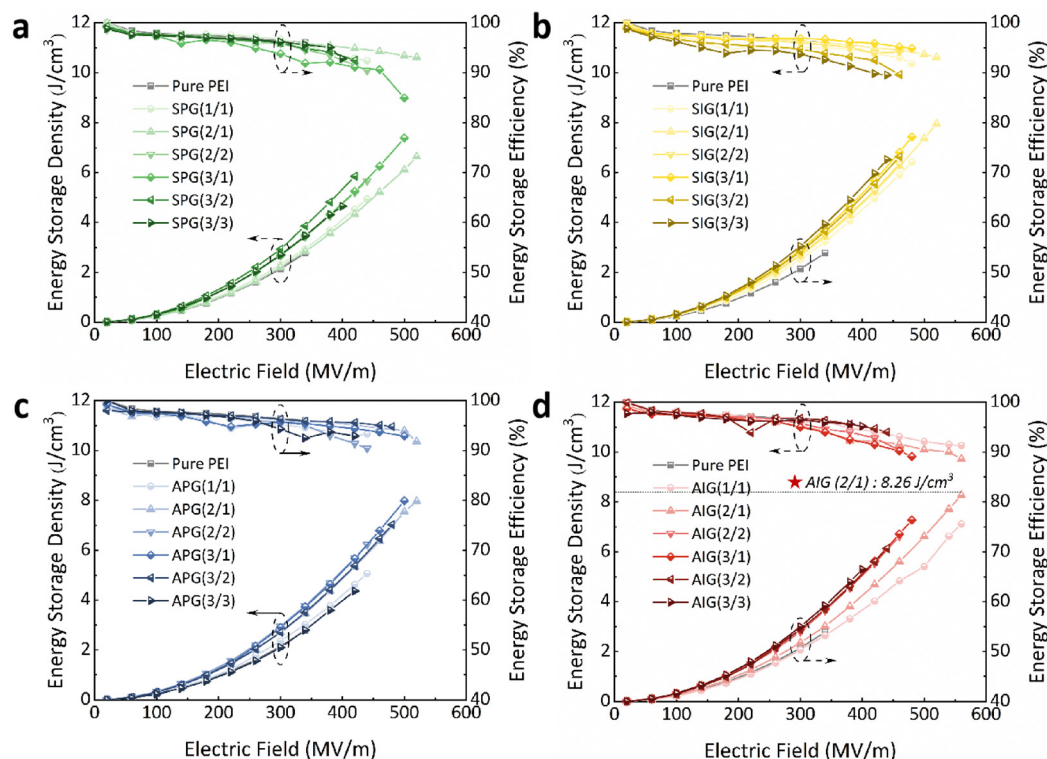


Fig. 4 The energy storage density and efficiency as a function of the electric field of (a) SPG, (b) SIG, (c) APG, and (d) AIG composite dielectrics.

upper electrode to the electric field, promotes the  $U_e$  of the AIG (2/1) composite dielectric significantly. The  $\eta$  of all polymer dielectrics gradually decreases with increasing electric field since the energy loss is caused by the space charge effect. Because of a certain degree of correlation between the  $\tan \delta$  and  $\eta$  of the polymer,<sup>36</sup> most gradient composite dielectrics maintain a higher  $\eta$  of  $\sim 90\%$  benefit from the lower  $\tan \delta$ . Nevertheless, certain composite dielectrics exhibit lower  $\eta$ , with

some experiencing an unavoidable decline under high electric fields, while others are due to their gradient composition. The single-layer PEI-based composite dielectric with a higher BNNSs content leads to higher polarization, and the  $\tan \delta$  also increases (Fig. S11 in the ESI<sup>†</sup>). Consequently, the gradient structure containing the single-layer composite dielectric with a higher BNNSs content exhibits a slightly lower  $\eta$ , but still higher than  $\sim 85\%$ .

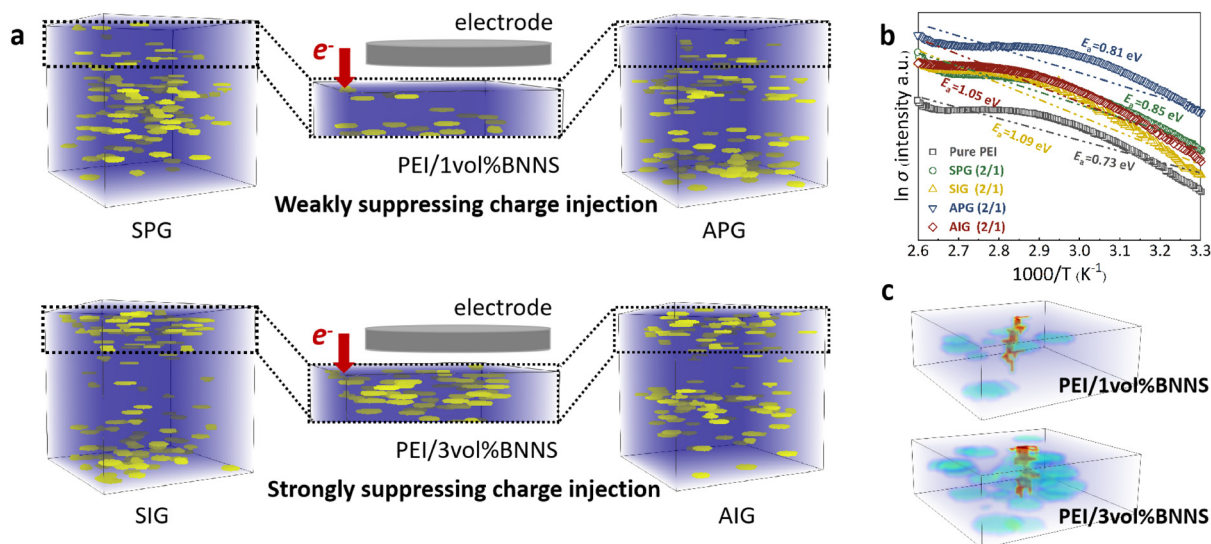


Fig. 5 (a) Schematic diagram of the metal/dielectric interface. (b) Dependence of  $\ln \sigma$  on  $1000/T$  for the pure PEI, SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at  $10^2$  Hz. (c) Development of the breakdown path in the surface barrier layer.

To enhance the understanding of the mechanism behind carrier injection and transport inhibition by the topological gradient structure, a schematic of the metal electrode/dielectric interface was plotted, as shown in Fig. 5a. Taking the best performance series as examples, including SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics, irrespective of whether it is symmetric or asymmetric, the BNNs content near the electrode/dielectric surface for the positive gradient composite dielectric is 1 vol%, while that of the inverse gradient composite dielectric is 3 vol%. The  $E_b$  values of both PEI/1 vol% BNNs ( $505.5 \text{ MV m}^{-1}$ ) and PEI/3 vol% BNNs ( $546.4 \text{ MV m}^{-1}$ ) composite dielectrics are higher than that of pure PEI ( $400.5 \text{ MV m}^{-1}$ ). Therefore, the barrier height can be raised and charge injection can be slowed down by using the PEI/1 vol% BNNs or PEI/3 vol% BNNs composite dielectric as a surface barrier layer. Furthermore, the PEI/3 vol% BNNs composite dielectric has a higher  $E_b$  than the PEI/1 vol% BNNs composite dielectric, thus the inverse gradient structure can effectively inhibit carrier injection.

When carriers are injected across the barrier height into the interior of the dielectric, the breakdown path develops slowly owing to the lower electric field and fewer carriers in the early transport process. Therefore, the surface barrier layer can secondarily block the breakdown path development in the early stage of carrier transport. The conductivity activation energy ( $E_a$ ) can reflect the minimum energy barrier that the carrier needs to overcome during the early stage of transport. The conductive activation energy of the pure PEI and gradient composite dielectrics was obtained using a dielectric spectrometer at varied temperatures.<sup>37,38</sup> Fig. 5b shows the dependence of  $\ln \sigma$  on  $1000/T$  for pure PEI and gradient composite dielectrics at  $10^2 \text{ Hz}$ , which is well described using the Arrhenius equation.<sup>39</sup> According to Arrhenius' law, the  $\sigma$

depends strongly on the temperature ( $T$ ), and the dependence equation can be written as follows:

$$\sigma(T) = \sigma_0 \exp(-E_a/kT) \quad (4)$$

where  $\sigma_0$  is the pre-exponential term and represents the high-temperature limit of  $\sigma$ ,  $k$  is the Boltzmann constant, and  $T$  is the absolute temperature. The  $E_a$  of pure PEI is only 0.73 eV, while the  $E_a$  values of SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) are 0.85, 1.09, 0.81, and 1.05 eV, respectively. The increasing  $E_a$  reflects that carriers need to overcome higher energy barriers to move after crossing the barrier height, especially in the inverse gradient structure. The stochastic breakdown model was employed to simulate the breakdown path development in the surface barrier layers of both positive and inverse gradient structures, providing intuitive insights into the block imposed by the surface barrier layer during the early stage of carrier transport, as shown in Fig. 5c. When the carrier injection from the metal electrode crosses the barrier into the dielectric, the initial breakdown point appears on the dielectric surface. As the applied electric field increases, the breakdown path gradually develops. Notably, the surface barrier layer in the inverse gradient structure exhibits a stronger obstruction effect, which is a more tortuous breakdown path, and the effective interception and secondary obstruction effect are formed during the early stage of the carrier transport.

The stochastic breakdown model was employed to simulate the breakdown path development of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics and further find out the strengthening effect on the inhibition of carrier transport, as shown in Fig. 6a and Fig. S20 (in the ESI†). Compared with SIG (2/1) and AIG (2/1) composite dielectrics, the surface barrier layer of the SPG (2/1) and APG (2/1) compo-

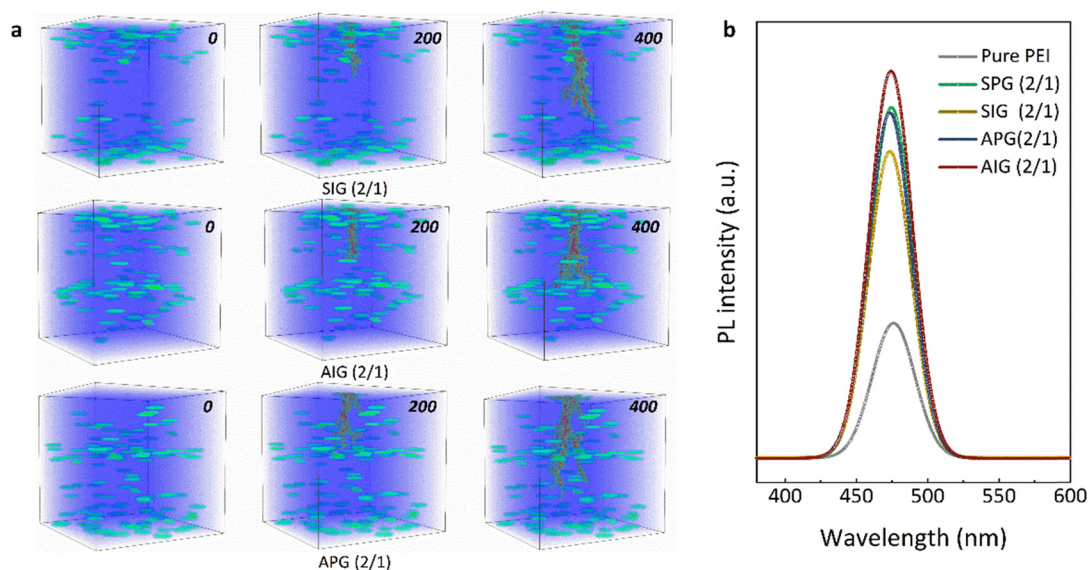


Fig. 6 (a) Dynamic breakdown path development in SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics. (b) Photoluminescence spectra of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics.



site dielectrics has a weaker blocking effect on carrier transport in the early stage, which accelerates breakdown path development. With the increasing electric field, as the breakdown path develops towards the central region, the central hinder layer in the asymmetric gradient structure exhibits a stronger block effect, which shows that the breakdown path pattern of APG and AIG composite dielectrics becomes divergent. The surface barrier layer of the AIG (2/1) composite dielectric has blocked and slowed down the carrier, resulting in a more divergent breakdown path when it reaches the dielectric center and touches the hinder layer. Since both the surface barrier layer and center hinder layer can block and slow down the carriers, the component units of the AIG (2/1) composite dielectric reduce the distance between the surface barrier layer and central hinder layer, and make them appear in the early and middle stages of the carrier transport. Thus, it reduces the free acceleration distance of the carriers and lowers the carrier energy. In contrast, the component units of the SIG (2/1) composite dielectric enlarged the distance between the surface barrier layer and the central hinder layer, which makes the free acceleration distance of the carrier longer and the accelerated energy higher.<sup>40</sup> In addition, by comparing the photoluminescence (PL) spectra of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics, the effect of the central hinder layer on carrier transport was further analyzed, as shown in Fig. 6b. A low PL intensity indicates stronger PL quenching, which in turn indicates higher carrier mobility.<sup>41</sup> It can be seen that the pure PEI has a lower intensity, indicating the highest internal carrier mobility, while the AIG (2/1) composite dielectric has the highest intensity and lowest carrier mobility. It is noted that the SIG (2/1) composite dielectric

shows a lower intensity compared with other gradient composite dielectrics, indicating that the component units cannot effectively block carrier transport. These results show that the appropriate construction of the asymmetric gradient structure can effectively inhibit carrier injection and transport simultaneously.

As the most widely used commercial dielectric capacitor, the optimal working temperature of BOPP is only 70 °C. When the temperature exceeds 105 °C, the insulation performance of BOPP will decrease dramatically. Mitigating temperature rises requires additional cooling devices, adding space and cost. It is urgent to consider the effect of high temperature on high-energy storage polymer-based composite dielectrics to meet applications in high-temperature environments in fields such as aerospace and new energy vehicles. Therefore, the topological gradient structure series with the best performance at room temperature was selected to further analyze the dielectric and energy storage performances at high temperatures. Fig. 7a and Fig. S21 (ESI<sup>†</sup>) show the  $\epsilon_r$  and  $\tan \delta$  of pure PEI, SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at different frequencies as a function of temperature. As the temperature increases, the thermal motion of molecules inside the polymer dielectrics gains reinforcement, weakening the interaction force between molecules and resulting in an increasing polarization degree. Meanwhile, the electric field changes faster with the increased temperature, which corresponds to the dipole moment turnover rate slowing down. This makes the  $\epsilon_r$  growth rate at high frequency lower than that at low frequency. Compared with the positive gradient structure, a large number of BNNSs in the inverse gradient structure are concentrated on both sides of the dielectric, effectively slowing down the thermal motion of the molecules inside the dielectric, resulting in a

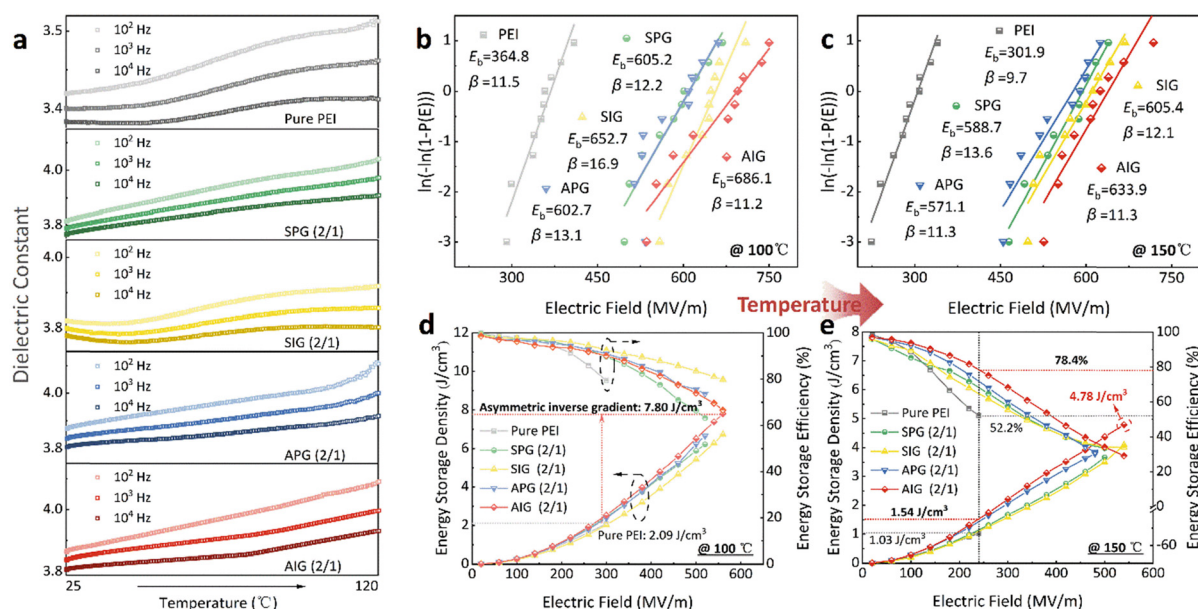


Fig. 7 (a) The temperature dependence of the dielectric constant of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at  $10^2$ ,  $10^3$ , and  $10^4$  Hz. The breakdown strength of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at (b) 100 °C and (c) 150 °C. The energy storage density and efficiency of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at (d) 100 °C and (e) 150 °C.

lower change in  $\epsilon_r$  with temperature, particularly evident in the SIG (2/1) composite dielectric. In addition, as the temperature increases, the  $\tan \delta$  of pure PEI and gradient structure composite dielectrics increases at all frequencies owing to the enhanced polarization effect, which may affect the energy storage efficiency at high temperatures.

The  $E_b$  values of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at 100 °C and 150 °C are shown in Fig. 7b and c, respectively. Compared with room temperature, the  $E_b$  of all dielectrics has different degrees of decline. However, compared with pure PEI, the  $E_b$  decline rate of the composite dielectric is lower. This is attributed to the fact that BNNs have a higher thermal conductivity, because of which, they can quickly dissipate the heat generated by the loss under high temperatures and high electric fields. As the temperature further increases to 150 °C, the  $E_b$  of all polymer dielectrics decreases rapidly. The interface structure of BNNs and the PEI matrix is prone to damage at high temperatures owing to the larger thermal expansion coefficient of the BNNs. It is noted that the gradient composite dielectric still maintains a higher  $E_b$  at high temperatures, which is conducive to improving high-temperature energy storage performance. For example, the AIG (2/1) composite dielectric achieves a highest  $E_b$  of 686.1 MV m<sup>-1</sup> and 633.9 MV m<sup>-1</sup> at 100 °C and 150 °C, respectively. Finally, the high-temperature energy storage performance of several dielectrics was tested. The  $U_e$  and  $\eta$  of pure PEI, and SPG (2/1), SIG (2/1), APG (2/1), and AIG (2/1) composite dielectrics at 100 °C and 150 °C are shown in Fig. 7d and e, respectively. Combined with the dielectric and breakdown performances of the gradient composite dielectric under high temperatures, unsurprisingly, the AIG (2/1) composite dielectric achieves excellent energy storage performance with the highest  $U_e$  of 7.80 J cm<sup>-3</sup> at 560 MV m<sup>-1</sup> and 100 °C, which is 3.7 times that of pure PEI. In addition, the  $U_e$  of the AIG (2/1) composite dielectric can reach 4.78 J cm<sup>-3</sup> at 150 °C, which is much higher than those of the dielectrics reported in previous studies.<sup>42–45</sup> When compared with pure PEI in the same electric field (240 MV m<sup>-1</sup>), the  $U_e$  and  $\eta$  of the AIG (2/1) composite dielectric can reach 1.54 J cm<sup>-3</sup> and 78.4%, respectively, which are significantly higher than those of pure PEI (1.03 J cm<sup>-3</sup> and 52.4%). By using a simple preparation strategy of alternate electrospinning process, the distribution characteristics of BNNs can be regulated to achieve higher breakdown strength and energy storage performances at room temperature and high temperature without additional interface modification or processing technology.

## 4. Conclusions

In summary, an intelligent and effective design route was demonstrated to develop PEI-based composite dielectric capacitors with higher breakdown strength and excellent energy storage performance working at room temperature to 150 °C based on stochastic breakdown simulation and adjustment of filler distribution characteristics. After the high-throughput

simulation shortened the experiment cycle, by adjusting the asymmetric gradient distribution of BNNs, constructing the surface barrier layer and central hinder layer, the breakdown strength and energy storage density were substantially enhanced. Higher energy storage density values of 8.26 J cm<sup>-3</sup> and 4.78 J cm<sup>-3</sup> were achieved at room temperature and 150 °C, respectively. Reducing the distance between the surface barrier layer and central hinder layer and increasing the height of the carrier injection barrier, as well as reducing the free acceleration distance of the carrier and minimizing the carrier energy, are the keys to significantly improving the performance. This work provides a strategy with simple and quantifiable production for high-energy storage dielectric capacitors.

## Author contributions

Dong Yue: writing – original draft, writing – review & editing, software, and formal analysis. Wenchao Zhang: conceptualization and supervision. Puzhen Wang: validation. Yong Zhang: formal analysis. Yu Teng: investigation. Jinghua Yin: methodology. Yu Feng: conceptualization, supervision, and writing – review & editing.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

Thanks to Prof. Sergey Maksimenko from the Belarusian State University for the physical model. This work was supported by the National Natural Science Foundation of China (No. 52177017), the National Key R&D Program of China (2022YFB2502602), the Natural Science Foundation of Heilongjiang Province of China (No. YQ2021E036), and the University Nursing Program for Young Scholars with Creative Talents in Heilongjiang Province (No. UNPYSCT-2020177).

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